

**SN54BCT541, SN74BCT541
OCTAL BUFFERS/DRIVERS
WITH 3-STATE OUTPUTS**

SCBS011C - JULY 1988 - REVISED APRIL 1994

- State-of-the-Art BiCMOS Design
Significantly Reduces I_{CCZ}
- 3-State Outputs Drive Bus Lines or Buffer
Memory Address Registers
- P-N-P Inputs Reduce DC Loading
- Data Flow-Through Pinout (All Inputs on
Opposite Side From Outputs)
- Package Options Include Plastic
Small-Outline (DW) Packages, Ceramic
Chip Carriers (FK) and Flatpacks (W), and
Plastic and Ceramic 300-mil DIPs (J, N)

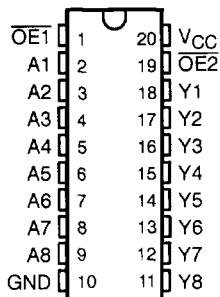
description

The 'BCT541 octal buffer and line driver is ideal for driving bus lines or buffering memory address registers. The device features inputs and outputs on opposite sides of the package to facilitate printed-circuit-board layout.

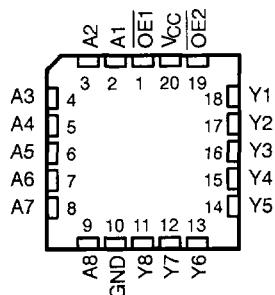
The 3-state control gate is a 2-input AND gate with active-low inputs so that if either output-enable (\overline{OE}_1 or \overline{OE}_2) input is high, all eight outputs are in the high-impedance state.

The SN54BCT541 is characterized for operation over the full military temperature range of -55°C to 125°C . The SN74BCT541 is characterized for operation from 0°C to 70°C .

**SN54BCT541 . . . J OR W PACKAGE
SN74BCT541 . . . DW OR N PACKAGE
(TOP VIEW)**



**SN54BCT541 . . . FK PACKAGE
(TOP VIEW)**



FUNCTION TABLE

INPUTS			OUTPUT
\overline{OE}_1	\overline{OE}_2	A	Y
L	L	L	L
L	L	H	H
H	X	X	Z
X	H	X	Z

PRODUCTION DATA information is current as of publication date.
Products conform to specifications per the terms of Texas Instruments
standard warranty. Production processing does not necessarily include
testing of all parameters.

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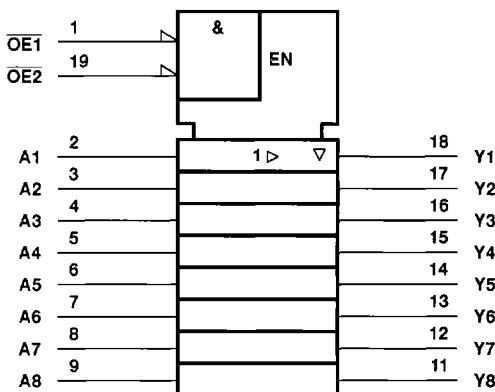
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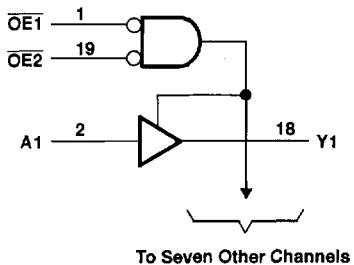
SN54BCT541, SN74BCT541 OCTAL BUFFERS/DRIVERS WITH 3-STATE OUTPUTS

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logic symbol



logic diagram (positive logic)



[†]This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V_{CC}	- 0.5 V to 7 V
Input voltage range, V_I (see Note 1)	- 0.5 V to 7 V
Voltage range applied to any output in the disabled or power-off state, V_O	- 0.5 V to 5.5 V
Voltage range applied to any output in the high state, V_O	- 0.5 V to V_{CC}
Current into any output in the low state: SN54BCT541	96 mA
	SN74BCT541
Operating free-air temperature range:	SN54BCT541
	SN74BCT541
Storage temperature range	- 65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

recommended operating conditions

		SN54BCT541			SN74BCT541			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	
V _{CC}	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
V _{IH}	High-level input voltage		2			2		V
V _{IL}	Low-level input voltage			0.8			0.8	V
I _{IK}	Input clamp current			-18			-18	mA
I _{OH}	High-level output current			-12			-15	mA
I _{OL}	Low-level output current			48			64	mA
T _A	Operating free-air temperature	-55	125	0	70			°C



electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	SN54BCT541			SN74BCT541			UNIT
		MIN	TYP†	MAX	MIN	TYP†	MAX	
V _{IK}	V _{CC} = 4.5 V, I _I = -18 mA			-1.2			-1.2	V
V _{OH}	V _{CC} = 4.5 V	I _{OH} = -3 mA	2.4	3.3	2.4	3.3		V
		I _{OH} = -12 mA	2	3.2				
		I _{OH} = -15 mA			2	3.1		
V _{OL}	V _{CC} = 4.5 V	I _{OL} = 48 mA	0.38	0.55				V
		I _{OL} = 64 mA			0.42	0.55		
I _I	V _{CC} = 5.5 V, V _I = 7 V		0.1		0.1		mA	
I _{IH}	V _{CC} = 5.5 V, V _I = 2.7 V		20		20		μA	
I _{IL}	V _{CC} = 5.5 V, V _I = 0.5 V		-0.6		-0.6		mA	
I _{OZH}	V _{CC} = 5.5 V, V _O = 2.7 V		50		50		μA	
I _{OZL}	V _{CC} = 5.5 V, V _O = 0.5 V		-50		-50		μA	
I _{OS‡}	V _{CC} = 5.5 V, V _O = 0	-100	-225	-100	-225		mA	
I _{CCH}	V _{CC} = 5.5 V		27	40	27	40	mA	
I _{CCL}	V _{CC} = 5.5 V		47	72	47	72	mA	
I _{CCZ}	V _{CC} = 5.5 V		5	7	5	7	mA	
C _i	V _{CC} = 5 V, V _I = 2.5 V or 0.5 V		5		5		pF	
C _o	V _{CC} = 5 V, V _O = 2.5 V or 0.5 V		10		10		pF	

† All typical values are at V_{CC} = 5 V, T_A = 25°C.

‡ Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

switching characteristics (see Note 2)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V _{CC} = 5 V, C _L = 50 pF, R ₁ = 500 Ω, R ₂ = 500 Ω, T _A = 25°C	V _{CC} = 4.5 V to 5.5 V, C _L = 50 pF, R ₁ = 500 Ω, R ₂ = 500 Ω, T _A = MIN to MAX§			UNIT		
			'BCT541			SN54BCT541	SN74BCT541		
			MIN	TYP	MAX	MIN	MAX		
t _{PLH}	A	Y	2.1	3.7	5.3	1.7	6.3	1.7	ns
			3.7	5.5	7.5	3.2	8.7	3.4	
t _{PHL}	OE	Y	5.3	7.2	9.3	4.4	11	4.6	ns
			6	8	10.4	5.4	12.4	5.4	
t _{PZH}	OE	Y	3.5	5.6	7.6	3	9.1	3	ns
			3.4	5.2	7.2	3	9.4	3	
t _{PZL}									

§ For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.



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